

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,727,190 B2
DATED : April 27, 2004
INVENTOR(S) : Anand Srinivasan et al.

Page 1 of 1

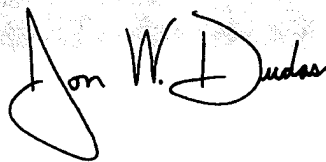
It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 6,

Line 29, replace "gas flow is 2,000 sccm, the deposition rate is" with -- gas flow rate is 2,000 sccm, the deposition rate is --.

Signed and Sealed this

Tenth Day of January, 2006

A handwritten signature in black ink, appearing to read "Jon W. Dudas". The signature is stylized with a large, sweeping initial "J" and a distinct "D".

JON W. DUDAS

Director of the United States Patent and Trademark Office